# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

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#### SURFACE MOUNT DUAL NPN SILICON MATCHED h<sub>FE</sub> TRANSISTORS





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## **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMKT5089M10 consists of two (2) individually isolated 5089 NPN silicon transistors with matched hFE. This ULTRAmini™ device is manufactured by the epitaxial planar process and epoxy molded in an SOT-363 surface mount package. The CMKT5089M10 has been designed for applications requiring high gain and low noise.

#### MARKING CODE: C9M0

MAXIMUM RATINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V <sub>CBO</sub>	30	V
Collector-Emitter Voltage	VCEO	25	V
Emitter-Base Voltage	VEBO	4.5	V
Continuous Collector Current	۱ <sub>C</sub>	50	mA
Power Dissipation	PD	350	mW
Operating and Storage Junction Temperature	TJ, Tstg	-65 to +150	°C
Thermal Resistance	$\Theta_{JA}$	357	°C/W

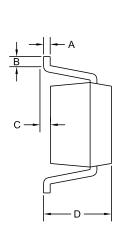
ELECTRICAL CHARACTERISTICS PER TRANSISTOR: (T <sub>A</sub> =25°C unless otherwise noted) SYMBOL TEST CONDITIONS MIN MAX UNITS							
I <sub>CBO</sub>	V <sub>CB</sub> =15V		50	nA			
IEBO	V <sub>EB</sub> =4.5V		100	nA			
BVCBO	I <sub>C</sub> =100μA	30		V			
BVCEO	I <sub>C</sub> =1.0mA	25		V			
BVEBO	I <sub>E</sub> =100μA	4.5		V			
V <sub>CE(SAT)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA		0.5	V			
V <sub>BE(SAT)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA		0.8	V			
h <sub>FE</sub>	V <sub>CE</sub> =5.0V, I <sub>C</sub> =0.1mA	400	1200				
h <sub>FE</sub>	V <sub>CE</sub> =5.0V, I <sub>C</sub> =1.0mA	450					
h <sub>FE</sub>	V <sub>CE</sub> =5.0V, I <sub>C</sub> =10mA	400					
fT	$V_{CE}$ =5.0V, I <sub>C</sub> =500µA, f=20MHz	50		MHz			
Cob	V <sub>CB</sub> =5.0V, I <sub>E</sub> =0, f=1.0MHz		4.0	pF			
C <sub>ib</sub>	$V_{BE}$ =0.5V, I <sub>C</sub> =0, f=1.0MHz		10	pF			
h <sub>fe</sub>	$V_{CE}$ =5.0V, I <sub>C</sub> =1.0mA, f=1.0kHz	450	1800				
NF	$V_{CE}$ =5.0V, I <sub>C</sub> =100µA, R <sub>S</sub> =1.0kΩ,						
	f=10Hz to 15.7kHz		2.0	dB			
MATCHING CHARACTERISTICS:							
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS			
	V <sub>CE</sub> =5.0V, I <sub>C</sub> =1.0mA	0.9	1.0				
VBE1-VBE2	V <sub>CE</sub> =5.0V, I <sub>C</sub> =100μA		5.0	mV			
* The lowest hFE re	ading is taken as hFE1.			R4 (13-January 2010)			

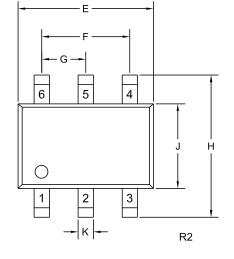


#### CMKT5089M10

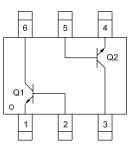
SURFACE MOUNT DUAL NPN SILICON MATCHED h<sub>FE</sub> TRANSISTORS

### SOT-363 CASE - MECHANICAL OUTLINE





#### **PIN CONFIGURATION**



LEAD CODE:

1) Emitter Q1 2) Base Q1

3) Collector Q2

- 4) Emitter Q2
- 5) Base Q2

6) Collector Q1

MARKING CODE: C9M0

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
А	0.004	0.010	0.10	0.25			
В	0.005	-	0.12	-			
С	0.000	0.004	0.00	0.10			
D	0.031	0.043	0.80	1.10			
E	0.071	0.087	1.80	2.20			
F	0.051		1.30				
G	0.026		0.65				
Н	0.075	0.091	1.90	2.30			
J	0.043	0.055	1.10	1.40			
K	0.006	0.012	0.15	0.30			
SOT-363 (REV: R2)							

R4 (13-January 2010)

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# OUTSTANDING SUPPORT AND SUPERIOR SERVICES

#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

#### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

#### REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### CONTACT US

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